

# PBSS4520X,135 Datasheet



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DiGi Electronics Part Number PBSS4520X,135-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PBSS4520X,135

Description TRANS NPN 20V 5A SOT89

Detailed Description Bipolar (BJT) Transistor NPN 20 V 5 A 125MHz 550 m

W Surface Mount SOT-89



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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
PBSS4520X,135	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	5 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
20 V	220mV @ 500mA, 5A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA	250 @ 2A, 2V
Power - Max:	Frequency - Transition:
550 mW	125MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Package / Case:	Supplier Device Package:
TO-243AA	SOT-89
Base Product Number:	
PBSS4520	

# **Environmental & Export classification**

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



**Product data sheet** 

# 1. General description

NPN low VCEsat transistor in a SOT89 (SC-62/TO-243) small and flat lead Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5520X

#### 2. Features and benefits

- High h<sub>FE</sub> and low V<sub>CEsat</sub> at high current operation
- High collector current capability: I<sub>C</sub> maximum 5 A
- Higher efficiency leading to less heat generation
- AEC-Q101 qualified

# 3. Applications

- Medium power peripheral drivers, e.g. fans and motors
- · Strobe flash units for DSC and mobile phones
- · Inverter applications, e.g. TFT displays
- · Power switch for LAN and ADSL systems
- Medium power DC-to-DC conversion
- Battery chargers

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	20	V
I <sub>C</sub>	collector current		-	-	5	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	10	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = 5 A; $I_B$ = 500 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	32	44	mΩ

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter		С
2	С	collector		
3	В	base	3 2 1	В — <b>Г</b>
			SOT89	sym123



20 V, 5 A NPN low VCEsat transistor

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package						
	Name	Description	Version				
PBSS4520X		plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89				

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS4520X	%1F

[1] % = placeholder for manufacturing site code

# 8. Limiting values

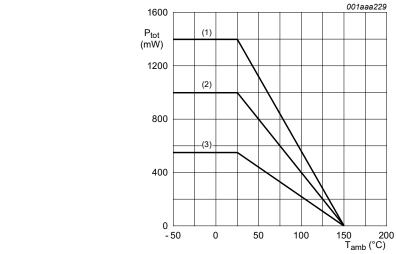
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	20	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	20	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
I <sub>C</sub>	collector current			-	5	Α
I <sub>CRM</sub>	repetitive peak collector current		[1] [2]	-	7	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	10	Α
I <sub>B</sub>	base current			-	1	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	2	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2] [3]	-	2.5	W
			[2]	-	0.55	W
			[4]	-	1	W
			[5]	-	1.4	W
			[6]	-	1.6	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Operated under pulsed conditions: pulse width  $t_p \le 10$  ms; duty cycle  $\delta \le 0.2$ .
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Operated under pulsed conditions:  $t_p \le 10$  ms;  $\delta \le 0.2$ .
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>
- [5] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [6] Device mounted on a 7 cm<sup>2</sup> ceramic PCB, 1 cm<sup>2</sup> single-sided copper and tin-plated.

#### 20 V, 5 A NPN low VCEsat transistor



- (1) FR4 PCB; 6 cm<sup>2</sup> mounting pad for collector (2) FR4 PCB; 1 cm<sup>2</sup> mounting pad for collector
- (3) FR4; standard footprint

**Power derating curves** Fig. 1.

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient		in free air	[1] [2]	-	-	50	K/W
	junction to ambient [1]	-	-	225	K/W		
		[3]	-	-	125	K/W	
	[4]	[4]	-	-	90	K/W	
		[5]	-	-	80	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	16	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Operated under pulsed conditions:  $t_p \le 10$  ms;  $\delta \le 0.2$ .
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>. [3]
- [4]
- Device mounted on a 7 cm<sup>2</sup> ceramic PCB, 1 cm<sup>2</sup> single-sided copper and tin-plated.

#### 20 V, 5 A NPN low VCEsat transistor

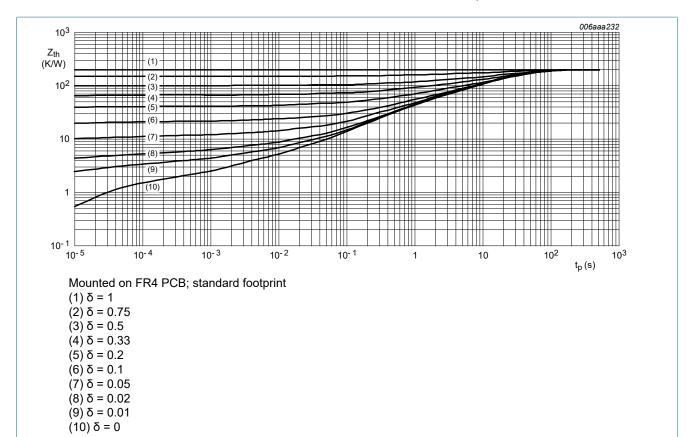
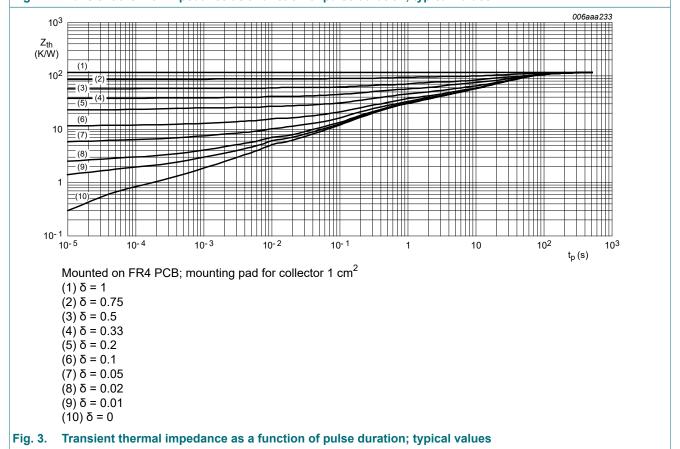
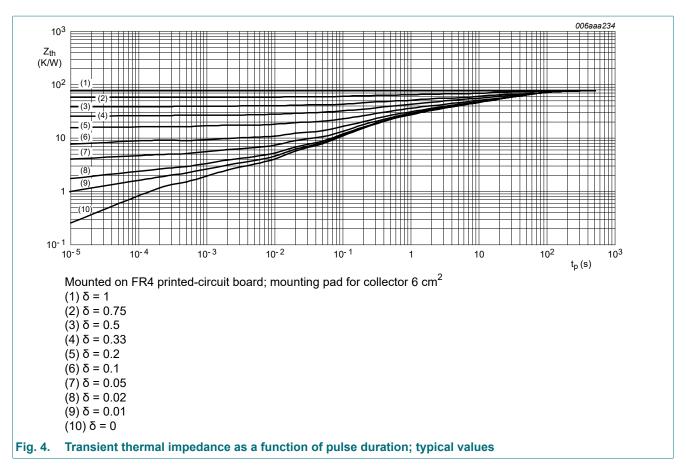


Fig. 2. Transient thermal impedance as a function of pulse duration; typical values



#### 20 V, 5 A NPN low VCEsat transistor



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# 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>СВО</sub>	collector-base cut-off	V <sub>CB</sub> = 20 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
	current	V <sub>CB</sub> = 20 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	50	μΑ
I <sub>ЕВО</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
CES	collector-emitter cut-off current	V <sub>CE</sub> = 20 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 0.5 A; T <sub>amb</sub> = 25 °C	300	450	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 1 A; pulsed; $t_{p}$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	300	440	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 2 A; pulsed; $t_{p} \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	250	420	-	
	$V_{CE}$ = 2 V; $I_{C}$ = 5 A; pulsed; $t_{p}$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_{amb}$ = 25 °C	200	380	-		
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = 0.5 A; I <sub>B</sub> = 5 mA; T <sub>amb</sub> = 25 °C	-	35	50	mV
saturation voltage	saturation voltage	I <sub>C</sub> = 1 A; I <sub>B</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	50	70	mV
		$I_C$ = 2.5 A; $I_B$ = 125 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	85	120	mV
	$I_C$ = 4 A; $I_B$ = 200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	130	180	mV	
		$I_C$ = 5 A; $I_B$ = 500 mA; pulsed; $t_p \le$	-	160	220	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	32	44	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = 4 A; $I_B$ = 200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	0.9	1.05	V
		$I_C$ = 5 A; $I_B$ = 500 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	0.96	1.1	V
$V_{BEon}$	base-emitter turn-on voltage	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 2 A; T <sub>amb</sub> = 25 °C	-	0.74	0.85	V
fт	transition frequency	$V_{CE}$ = 10 V; $I_{C}$ = 100 mA; f = 100 MHz; $T_{amb}$ = 25 °C	100	125	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C	-	90	110	pF

#### 20 V, 5 A NPN low VCEsat transistor

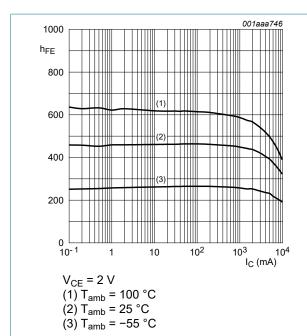


Fig. 5. DC current gain as a function of collector current; typical values

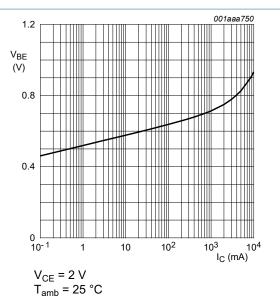


Fig. 6. Base-emitter voltage as a function of collector current; typical values

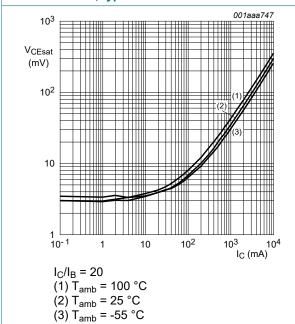


Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values

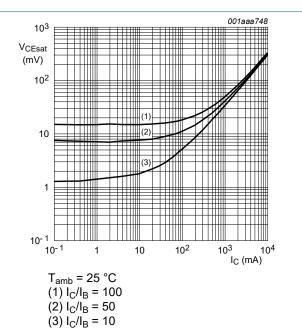


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

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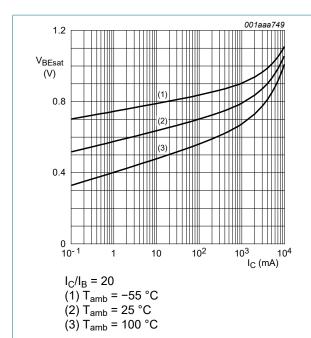
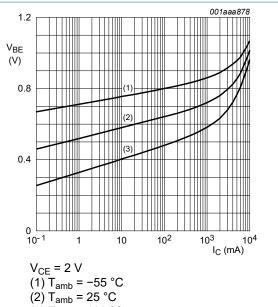
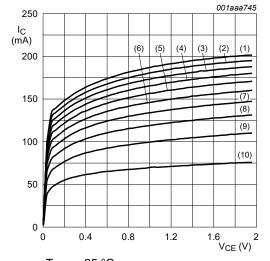


Fig. 9. collector current; typical values



(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Base-emitter saturation voltage as a function of Fig. 10. Base-emitter voltage as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

(1)  $I_B = 5 \text{ mA}$ 

 $(2) I_B = 4.5 \text{ mA}$ 

(3)  $I_B = 4 \text{ mA}$ 

(4)  $I_B = 3.5 \text{ mA}$ 

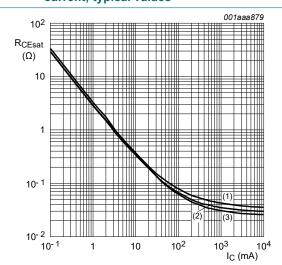
(5)  $I_B = 3 \text{ mA}$ (6)  $I_B = 2.5 \text{ mA}$ 

 $(7) I_B = 2 mA$ 

(8)  $I_B = 1.5 \text{ mA}$ (9)  $I_B = 1 \text{ mA}$ 

 $(10) I_B = 0.5 \text{ mA}$ 





 $I_{\rm C}/I_{\rm B} = 20$ 

(1) T<sub>amb</sub> = 100 °C

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig. 12. Equivalent on-resistance as a function of collector current; typical values

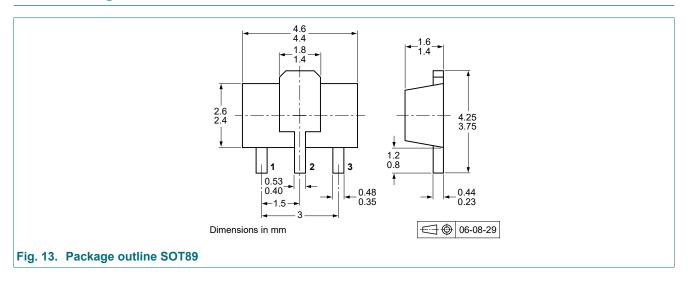
20 V, 5 A NPN low VCEsat transistor

### 11. Test information

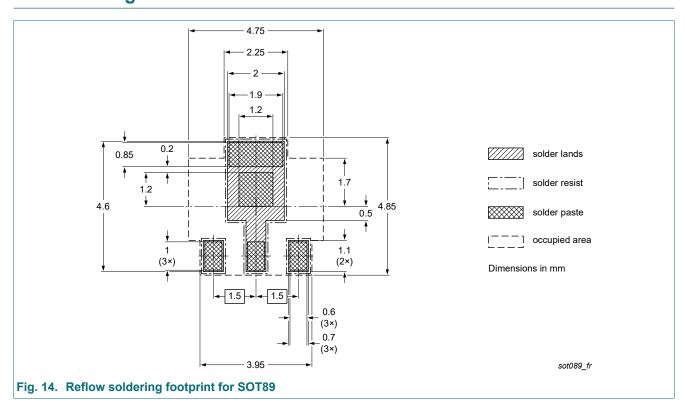
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

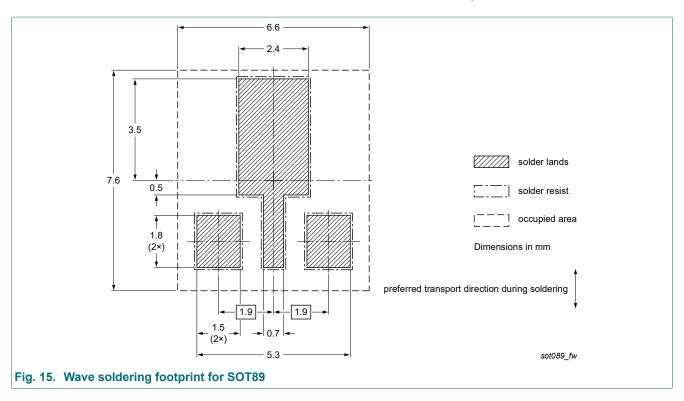
# 12. Package outline



# 13. Soldering



#### 20 V, 5 A NPN low VCEsat transistor



20 V, 5 A NPN low VCEsat transistor

# 14. Revision history

#### **Table 8. Revision history**

	· J			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4520X v.3	20240119	Product data sheet	-	PBSS4520X v.2
Modifications:	Nexperia.	ta sheet has been redesi n adapted to the new cor		, 0
PBSS4520X v.2	20041108	Product data sheet	-	PBSS4520X v.1
PBSS4520X v.1	20040611	Product data sheet	-	-

#### 20 V, 5 A NPN low VCEsat transistor

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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